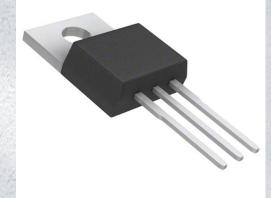


FQP16N25C Datasheet

www.digi-electronics.com



DiGi Electronics Part Number

Manufacturer

Manufacturer Product Number

Description

Detailed Description

FQP16N25C-DG

onsemi

FQP16N25C

MOSFET N-CH 250V 15.6A TO220-3

N-Channel 250 V 15.6A (Tc) 139W (Tc) Through Hol e TO-220-3

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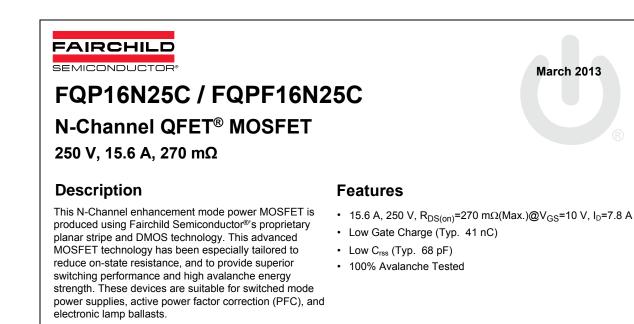


Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FQP16N25C	onsemi
Series:	Product Status:
QFET [®]	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
250 V	15.6A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	270mOhm @ 7.8A, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
4V @ 250μΑ	53.5 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	1080 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	139W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220-3	TO-220-3
Base Product Number:	
FQP1	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095





Absolute Maximum Ratings T_c = 25°C unless otherwise noted

Symbol	Parameter		FQP16N25C	FQPF16N25C	Unit
V _{DSS}	Drain-Source Voltage		250		V
I _D	Drain Current - Continuous (T _C = 25°C)	15.6	15.6 *	Α
	- Continuous (T _C = 100°	C)	9.8	9.8 *	А
I _{DM}	Drain Current - Pulsed	(Note 1)	62.4	62.4 *	А
V _{GSS}	Gate-Source Voltage		± 30		V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	410		mJ
I _{AR}	Avalanche Current	(Note 1)	15.6		А
E _{AR}	Repetitive Avalanche Energy (Note 1)		13.9		mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		5.5		V/ns
P _D	Power Dissipation ($T_C = 25^{\circ}C$)		139	43	W
	- Derate above 25°C		1.11	0.34	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150		°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300		°C
۱L					

Thermal Characteristics

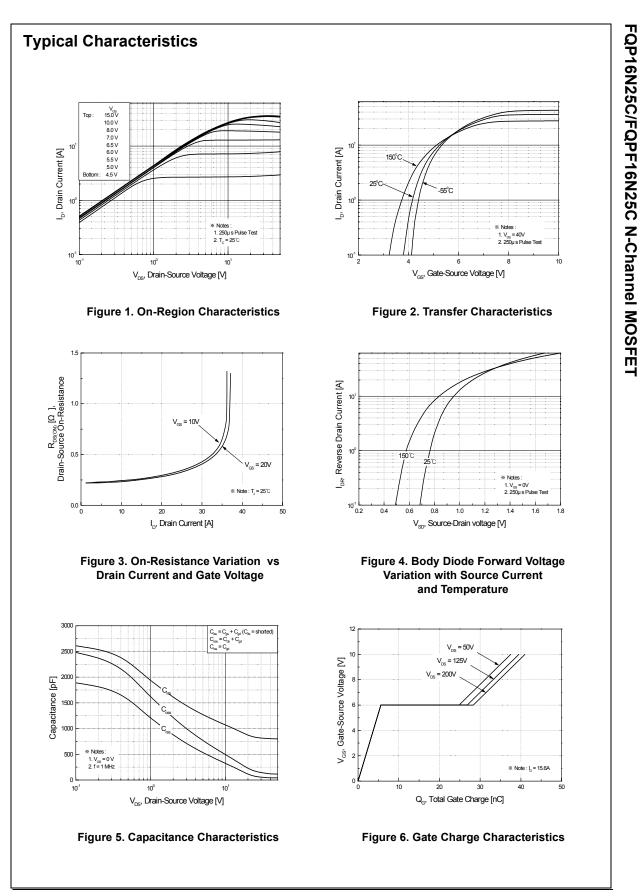
Symbol	Parameter	FQP16N25C	FQPF16N25C	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	0.9	2.89	°C/W	
$R_{\theta JS}$	Thermal Resistance, Case-to-Sink Typ.	0.5		°C/W	
R _{0JA}	Thermal Resistance, Junction-to-Ambient	62.5	62.5	°C/W	

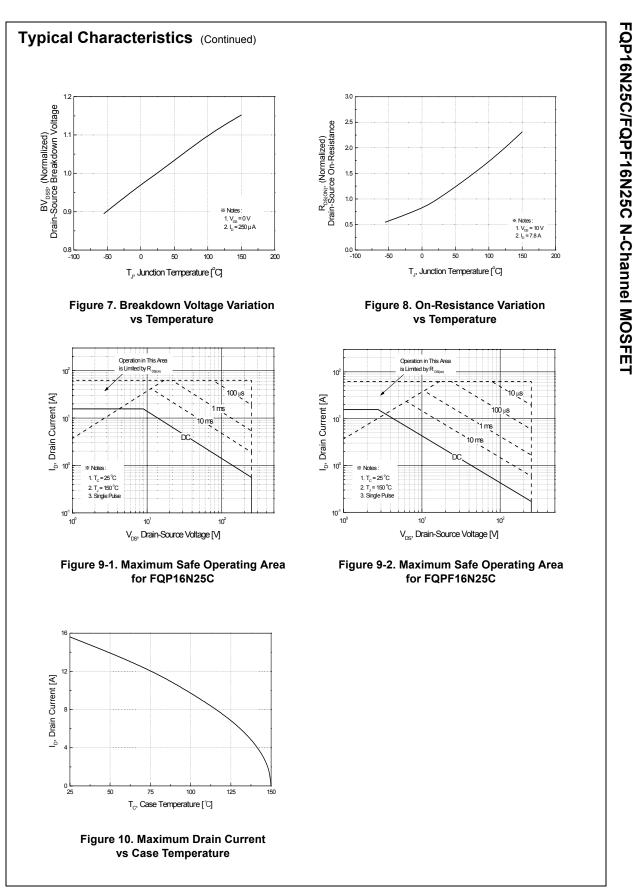
©2004 Fairchild Semiconductor Corporation FQP16N25C / FQPF16N25C Rev. C0

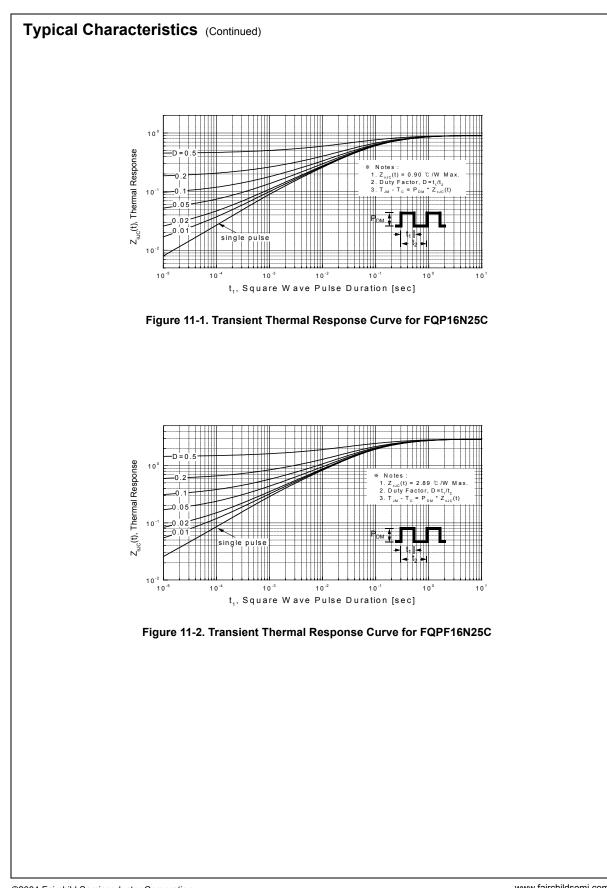
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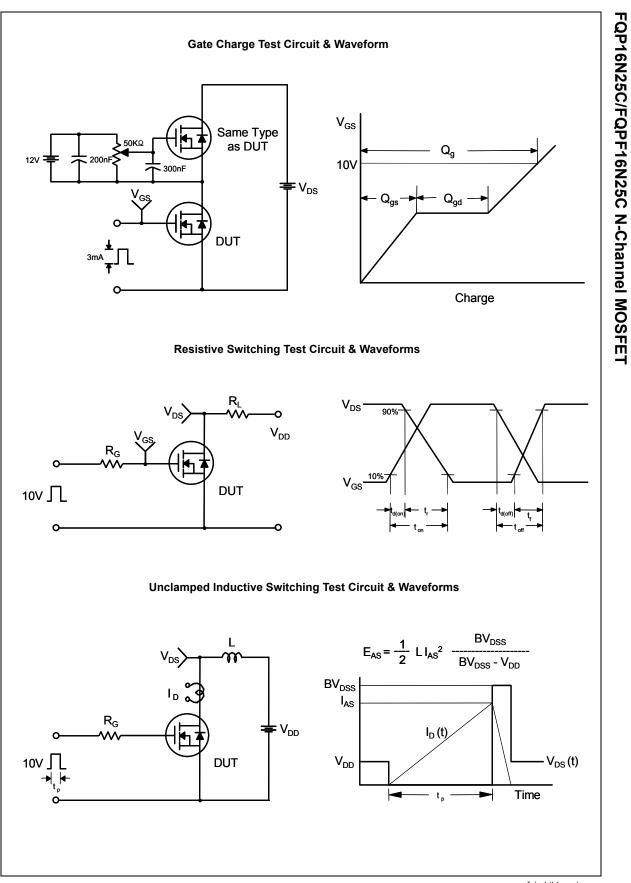
FQP16N25C/FQPF16N25C N-Channel MOSFET

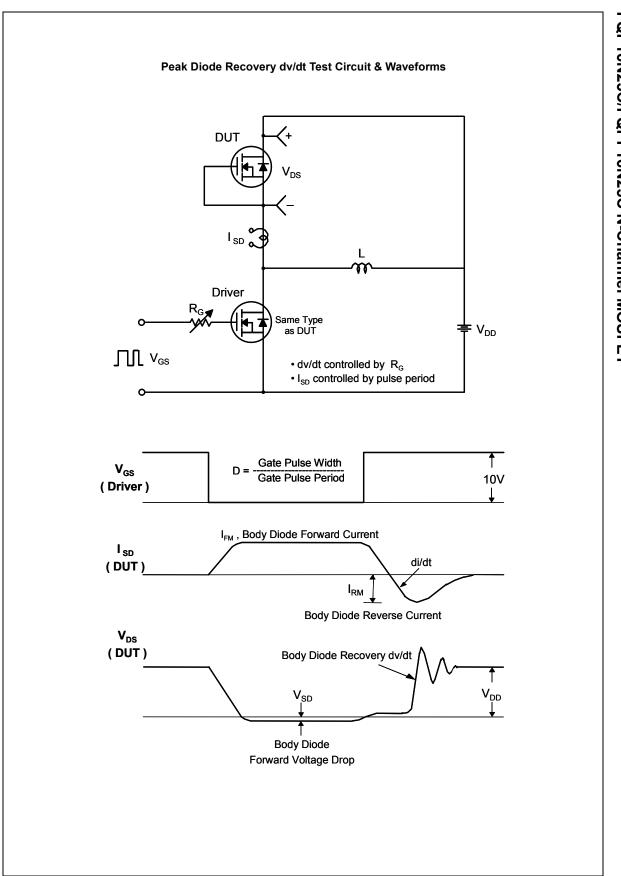
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	250			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C		0.31		V/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 250 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 200 \text{ V}, T_{C} = 125^{\circ}\text{C}$			10 100	μA μA
GSSF	Gate-Body Leakage Current, Forward	$V_{\rm GS} = 30 \text{ V}, V_{\rm DS} = 0 \text{ V}$			100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-100	nA
GSSK					100	
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 7.8 A		0.22	0.27	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 7.8 A (Note 4)		10.5		S
_						
	ic Characteristics		1		1000	_
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		830	1080	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		170	220	pF
C _{rss}	Reverse Transfer Capacitance			68	89	pF
Switchi	ing Characteristics		I		1	
t _{d(on)}	Turn-On Delay Time	V _{DD} = 125 V, I _D = 15.6 A,		15	40	ns
t _r	Turn-On Rise Time	$R_G = 25 \Omega$		130	270	ns
t _{d(off)}	Turn-Off Delay Time			135	280	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		105	220	ns
Qg	Total Gate Charge	V _{DS} = 200 V, I _D = 15.6 A,		41	53.5	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		5.6		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		22.7		nC
Drain_9	ource Diode Characteristics a	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Dic	•			15.6	А
I _{SM}	Maximum Pulsed Drain-Source Diode F				62.4	A
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 15.6 A			1.5	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 15.6 A,		260		ns
Q _{rr}	Reverse Recovery Charge	$dI_F / dt = 100 A/\mu s$ (Note 4)		2.47		μC
otes:			I		1	1
L = 2.7mH, I I _{SD} \leq 15.6A, Pulse Test :	ating : Pulse width limited by maximum junction tempe $_{AS} = 15.6A$, $V_{DD} = 50V$, $R_G = 25 \Omega$, Starting $T_J = 25^\circ C$ di/dt $\leq 300 A/\mu s$, $V_{DD} \leq 8V_{DSS}$, Starting $T_J = 25^\circ C$ Pulse width $\leq 300 \mu s$, Duty cycle $\leq 2\%$ ndependent of operating temperature					

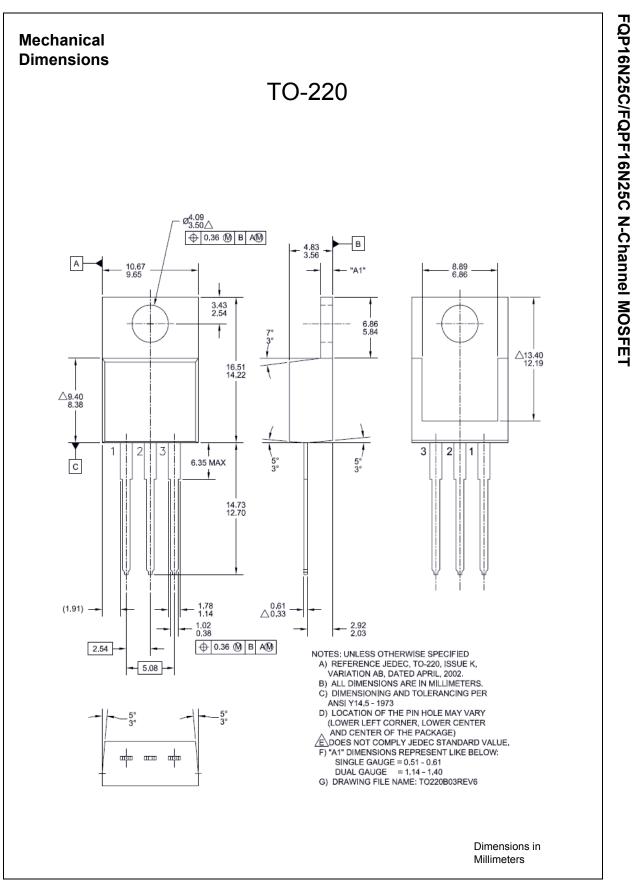


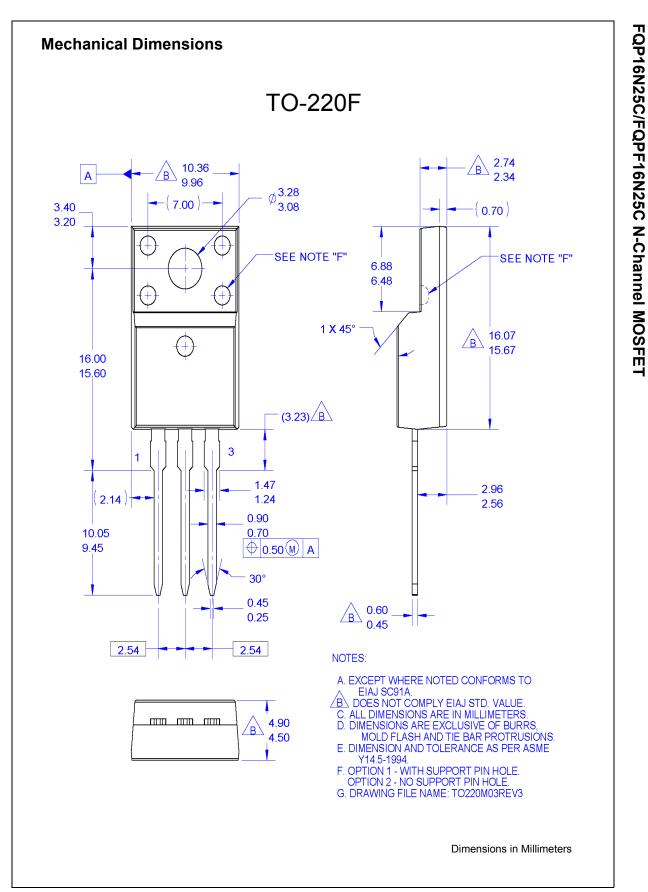


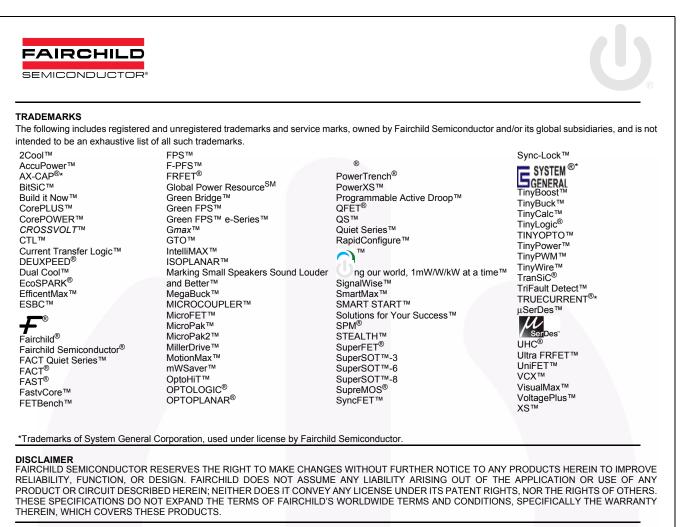












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